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CONFIRMATION NO. 5592

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|---|---|----------------------------------|---|--------------------------------------|
| SERIAL NUMBER 10/568,186 | FILING OR 371(c) DATE 03/03/2006 RULE | CLASS 117 | GROUP ART UNIT 1722 | ATTORNEY DOCKET NO. 126961 |
| APPLICANTS Izumi Fusegawa, Fukushima, JAPAN; Nobuaki Mitamura, Fukushima, JAPAN; Takahiro Yanagimachi, Fukushima, JAPAN; | | | | |
| ** CONTINUING DATA ***** This application is a 371 of PCT/JP04/11685 08/13/2004 | | | | |
| ** FOREIGN APPLICATIONS ***** JAPAN 2003-296837 08/20/2003 | | | | |
| IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 07/20/2006 | | | | |
| Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after met Verified and Acknowledged <i>Allowance</i> Examiner's Signature <i>PSH.</i> Initials | | STATE OR COUNTRY JAPAN | SHEETS DRAWING 5 | TOTAL CLAIMS 17 |
| | | | | INDEPENDENT CLAIMS 2 |
| ADDRESS 25944 | | | | |
| TITLE Method for producing a single crystal and silicon single crystal wafer | | | | |
| FILING FEE RECEIVED 1030 | FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following: | | <input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit | |